

LABORATORY GROWN DIAMOND REPORT

IGI LABORATORY GROWN DIAMOND IDENTIFICATION REPORT

May 31, 2023

IGI Report Number LG582359466

Description LABORATORY GROWN DIAMOND

Shape and Cutting Style CUT CORNERED RECTANGULAR MODIFIED RRILLIANT

5.69 X 4.44 X 3.03 MM

Measurements 5.69 X 4.44 X 3.03

GRADING RESULTS

Carat Weight 0.66 CARAT

Color Grade FANCY VIVID YELLOW

Clarity Grade VVS 2

ADDITIONAL GRADING INFORMATION

Polish VERY GOOD

Symmetry VERY GOOD

Fluorescence NONE

Inscription(s) 1/5/1 LG582359466

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High

Temperature (HPHT) growth process.

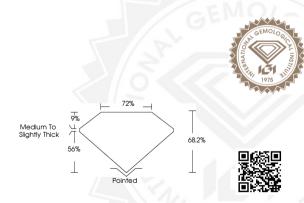
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Sample Image Used





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